

**Vishay Siliconix** 

# N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V <sub>DS</sub> (V)	<b>R<sub>DS(on)</sub> (</b> Ω <b>)</b>	I <sub>D</sub> (A)		
30	0.009 at V <sub>GS</sub> = 10 V	11		
	0.010 at V <sub>GS</sub> = 4.5 V	10		
	0.014 at V <sub>GS</sub> = 2.5 V	8.8		

### FEATURES

- Halogen-free
- TrenchFET<sup>®</sup> Power MOSFETS: 2.5 V Rated
- 30 V V<sub>DS</sub>

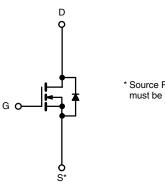


COMPLIANT

### **APPLICATIONS**

Battery SwitchCharger Switch

TSSOP-8 D 1 • 8 D S 2 Si6404DQ 7 S S 3 G 4 5 D Top View



\* Source Pins 2, 3, 6 and 7 must be tied common.

Ordering Information: Si6404DQ-T1-GE3 (Lead (Pb)-free and Halogen-free)

N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b> $T_A = 25 \text{ °C}$ , unless otherwise noted							
Parameter		Symbol	10 s	Steady State	Unit		
Drain-Source Voltage		V <sub>DS</sub>	30		V		
Gate-Source Voltage		V <sub>GS</sub>	± 12				
Continuous Drain Current (T 150 °C)a	T <sub>A</sub> = 25 °C	- I <sub>D</sub>	11	8.6			
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		8.9	6.9			
Pulsed Drain Current (10 µs Pulse Width)		I <sub>DM</sub>	30		A		
Continuous Source Current (Diode Conduction) <sup>a</sup>		۱ <sub>S</sub>	1.5	0.95			
Marine Draw Dissinglight	T <sub>A</sub> = 25 °C	– P <sub>D</sub>	1.75	1.08	W		
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C		1.14	0.69			
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55 to 150		°C		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Manimum landian la Andriana	t ≤ 10 s	R <sub>thJA</sub>	55	70	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady State		95	115	
Maximum Junction-to-Foot (Drain)	Steady State	R <sub>thJF</sub>	35	45	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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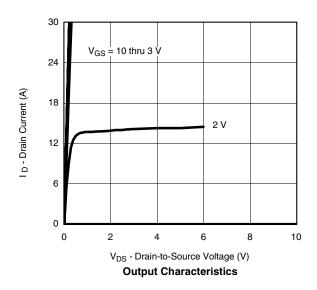
<b>SPECIFICATIONS</b> T <sub>J</sub> = 25 °C, unless otherwise noted									
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit			
Static			•						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}$ , $I_D = 250 \ \mu A$	0.6			V			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = \pm 12 V$			± 100	nA			
Zero Gate Voltage Drain Current		$V_{DS} = 24 V, V_{GS} = 0 V$			1				
	IDSS	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 ^{\circ}\text{C}$			10	μA			
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 10 V$	20			А			
Drain-Source On-State Resistance <sup>a</sup>		V <sub>GS</sub> = 10 V, I <sub>D</sub> = 11 A		0.0073	0.009				
	R <sub>DS(on)</sub>	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 10 A		0.0084	0.010	Ω			
		$V_{GS} = 2.5 \text{ V}, \text{ I}_{D} = 8.8 \text{ A}$		0.0116	0.014				
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 11 \text{ A}$		27		S			
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	$I_{\rm S} = 1.5$ A, $V_{\rm GS} = 0$ V		0.72	1.1	V			
Dynamic <sup>b</sup>									
Total Gate Charge	Qg			32	48	nC			
Gate-Source Charge	Q <sub>gs</sub>	$V_{DS}$ = 15 V, $V_{GS}$ = 4.5 V, $I_D$ = 11 A		8.1					
Gate-Drain Charge	Q <sub>gd</sub>			10		1			
Gate Resistance	Rg			7.5		Ω			
Turn-On Delay Time	t <sub>d(on)</sub>			35	55				
Rise Time	t <sub>r</sub>	$V_{DD}$ = 15 V, $R_L$ = 15 $\Omega$		35	55	ns			
Turn-Off Delay Time	t <sub>d(off)</sub>	$\text{I}_\text{D}\cong$ 1 A, $\text{V}_\text{GEN}$ = 4.5 V, $\text{R}_\text{G}$ = 6 $\Omega$		100	150				
Fall Time	t <sub>f</sub>			50	75				
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 1.5 A, di/dt = 100 A/μs		40	85				

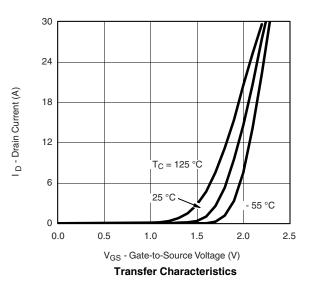
Notes:

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### TYPICAL CHARACTERISTICS 25 °C unless noted





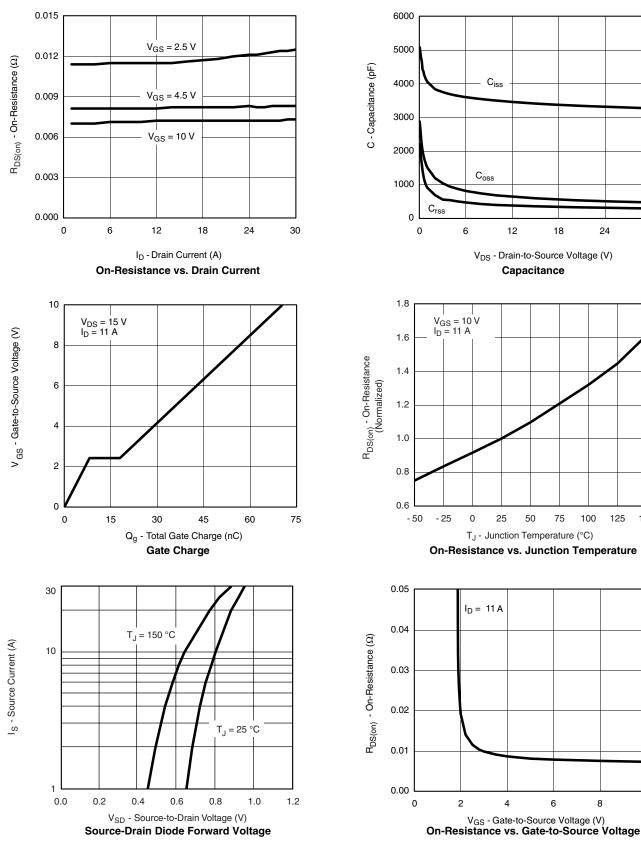




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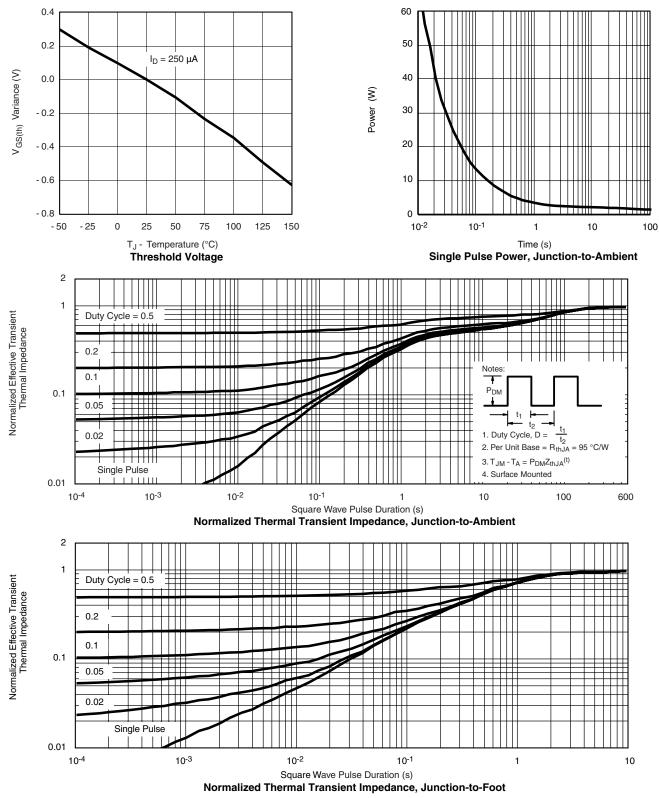
### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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### **Vishay Siliconix**





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